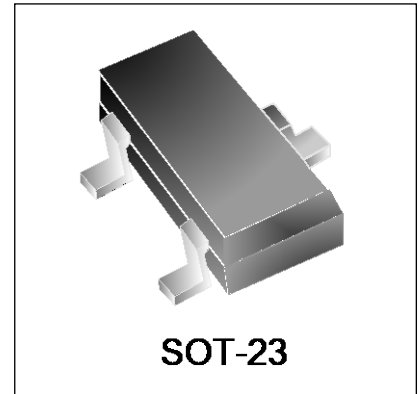


Features

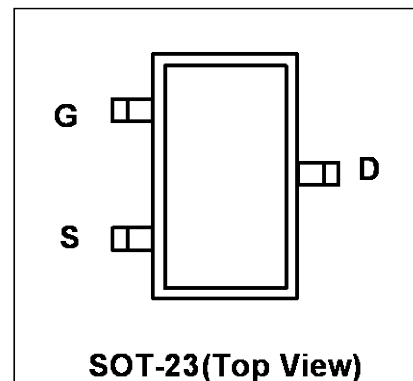
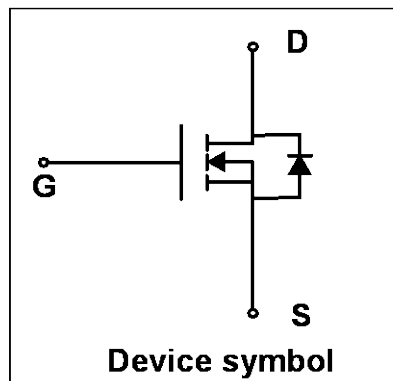
- Way-on Small Signal MOSFETs
- $V_{DS} = 20V$, $I_D = 3.1A$
 $R_{DS(on)} < 45m\Omega$ @ $V_{GS} = 4.5V$
 $R_{DS(on)} < 60m\Omega$ @ $V_{GS} = 2.5V$
- Trench LV MOSFET Technology

Mechanical Characteristics

- SOT-23 Package
- Marking : Making Code
- RoHS Compliant



Schematic & PIN Configuration



Absolute Maximum Rating ($T_A = 25^\circ C$ unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	± 8	V
Continuous Drain Current	$T_A = 25^\circ C$	I_D	3.1	A
Pulsed Drain Current ¹		I_{DM}	12.4	A
Power Dissipation	$T_A = 25^\circ C$	P_D	700	mW
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 150	$^\circ C$

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient ²	$R_{\theta JA}$	179	$^\circ C/W$

Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 250μA	20	-	-	V
Drain Cut-off Current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0 V	-	-	1	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±8V, V _{DS} = 0 V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{GS} = V _{DS} , I _D = 250μA	0.4	0.75	1.2	V
Drain-Source on-State Resistance ³	R _{DS(on)}	V _{GS} = 4.5V, I _D = 3.1A	-	33	45	mΩ
		V _{GS} = 2.5V, I _D = 2.5A	-	43	60	
Dynamic Characteristics ⁴						
Input Capacitance	C _{iss}	V _{GS} =0V, V _{DS} = 10V, f = 1 MHz	-	300	-	pF
Output Capacitance	C _{oss}		-	54	-	
Reverse Transfer Capacitance	C _{rss}		-	43	-	
Switching Characteristics ⁴						
Total Gate Charge	Q _g	V _{DS} = 10V, V _{GS} = 4.5V, I _D = 3A	-	2.9	-	nC
Gate-Source charge	Q _{gs}		-	0.4	-	
Gate-Drain Charge	Q _{gd}		-	0.6	-	
Turn-on Delay Time	t _{d(on)}	V _{GS} = 4.5V, V _{DS} = 10V, R _L = 3.3Ω, R _G = 6Ω	-	2.5	-	ns
Turn-on Rise Time	t _r		-	3.2	-	
Turn-off Delay Time	t _{d(off)}		-	21	-	
Turn- off Fall Time	t _f		-	3	-	
Source-Drain Diode characteristics						
Body Diode Voltage	V _{SD}	I _S = 1A, V _{GS} = 0V	-	-	1.2	V
Continuous Source Current	I _S		-	-	3.1	A

Notes:

1. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C
2. The data tested by surface mounted on a 1 inch² FR-4 board with 20Z copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.
4. This value is guaranteed by design hence it is not included in the production test.

Typical Characteristics

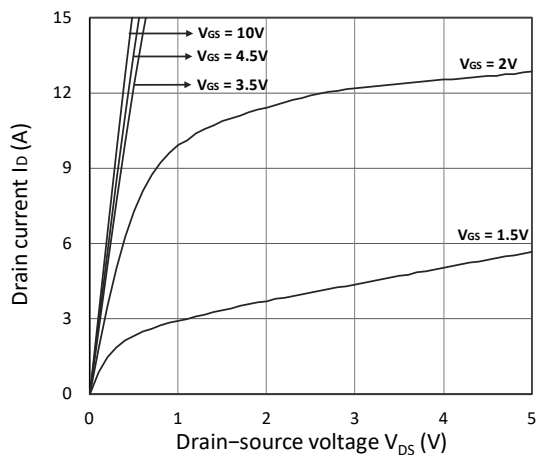


Figure 1. Output Characteristics

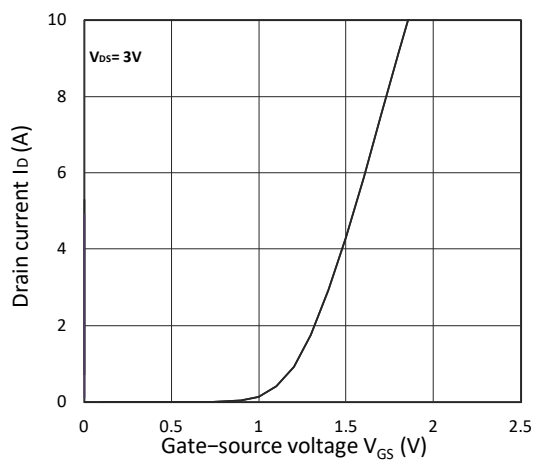


Figure 2. Transfer Characteristics

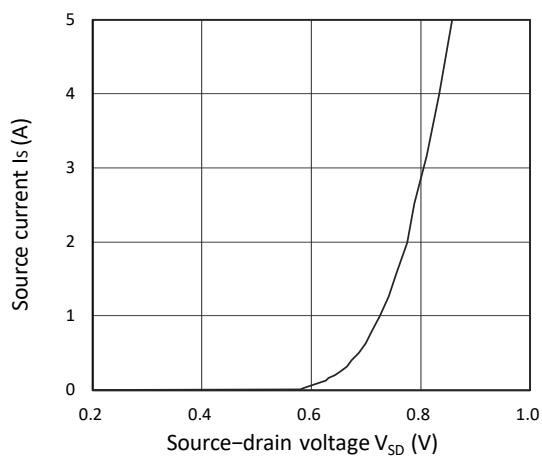
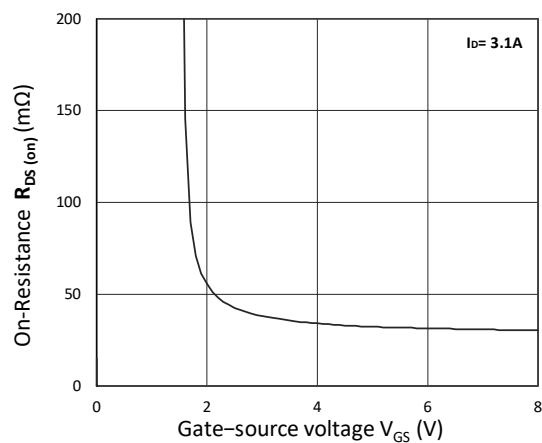
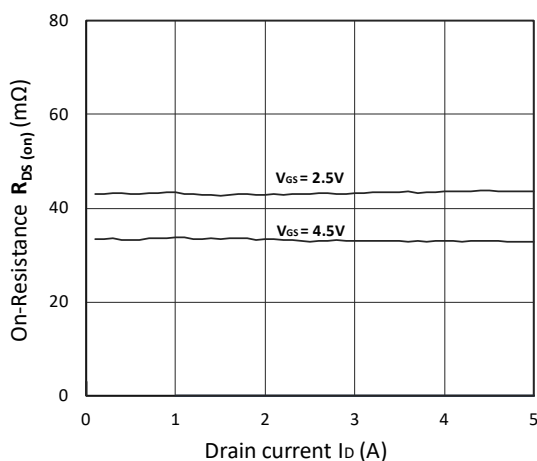
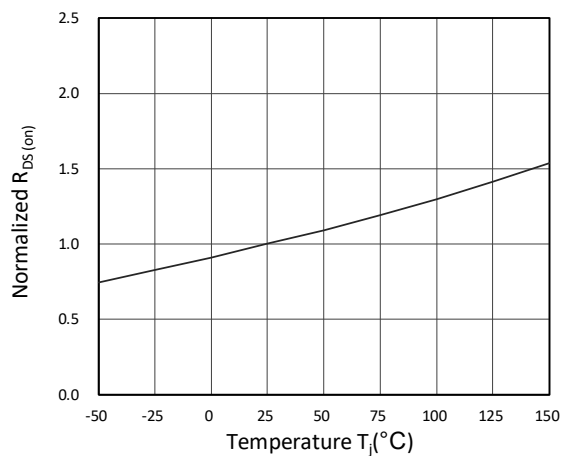
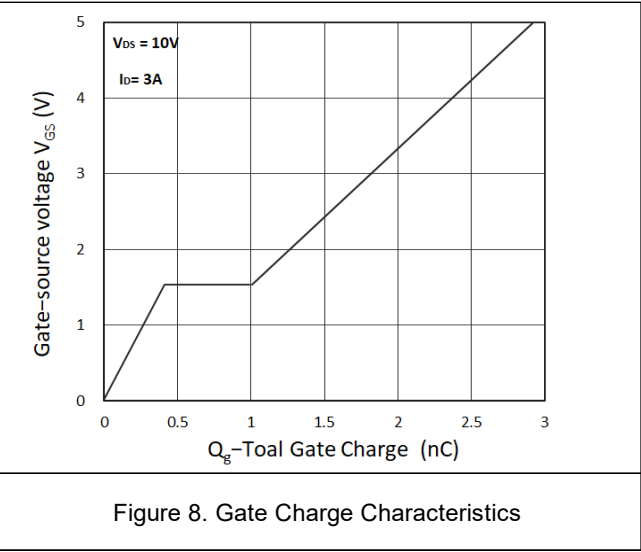
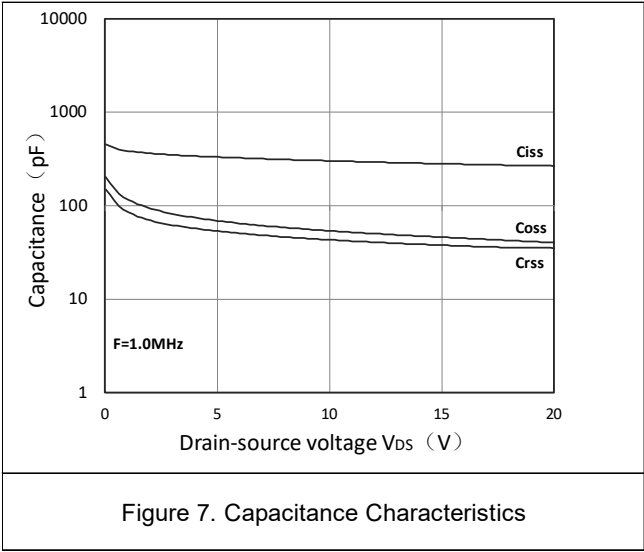


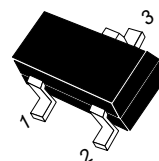
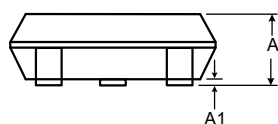
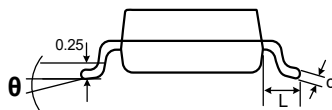
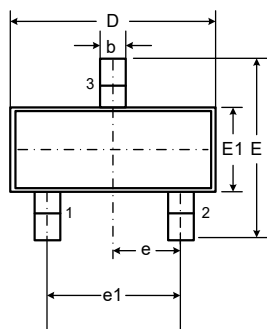
Figure 3. Forward Characteristics of Reverse

Figure 4. $R_{DS(on)}$ vs. V_{GS} Figure 5. $R_{DS(on)}$ vs. I_D Figure 6. Normalized $R_{DS(on)}$ vs. Temperature



Outline Drawing – SOT-23

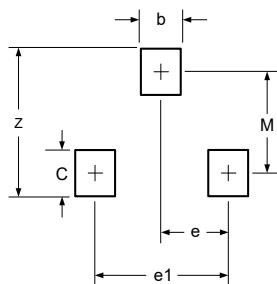
PACKAGE OUTLINE



SOT-23

DIMENSIONS

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.30	0.50	0.012	0.020
c	0.08	0.15	0.003	0.006
D	2.80	3.00	0.110	0.118
E	2.25	2.55	0.089	0.100
E1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.037BSC	
e1	1.80	2.00	0.071	0.079
L	0.55REF		0.022REF	
θ	0°	8°	0°	8°

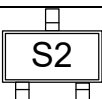


DIMENSIONS		
DIM	INCHES	MILLIMETERS
M	0.080	2.02
C	0.032	0.80
Z	0.111	2.82
e	0.037 BSC	0.95 BSC
e1	0.075 BSC	1.90 BSC
b	0.032	0.80

Notes

1. Dimensioning and tolerances per ANSI Y14.5M, 1985.
2. Controlling Dimension: Inches
3. Pin 3 is the cathode (Unidirectional Only).
4. Dimensions are exclusive of mold flash and metal burrs.

Marking Codes

Part Number	WM02N31M
Marking Code	

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

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WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.



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Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.